

MOSFETs Silicon P-Channel MOS (U-MOSVI)

TPCC8138

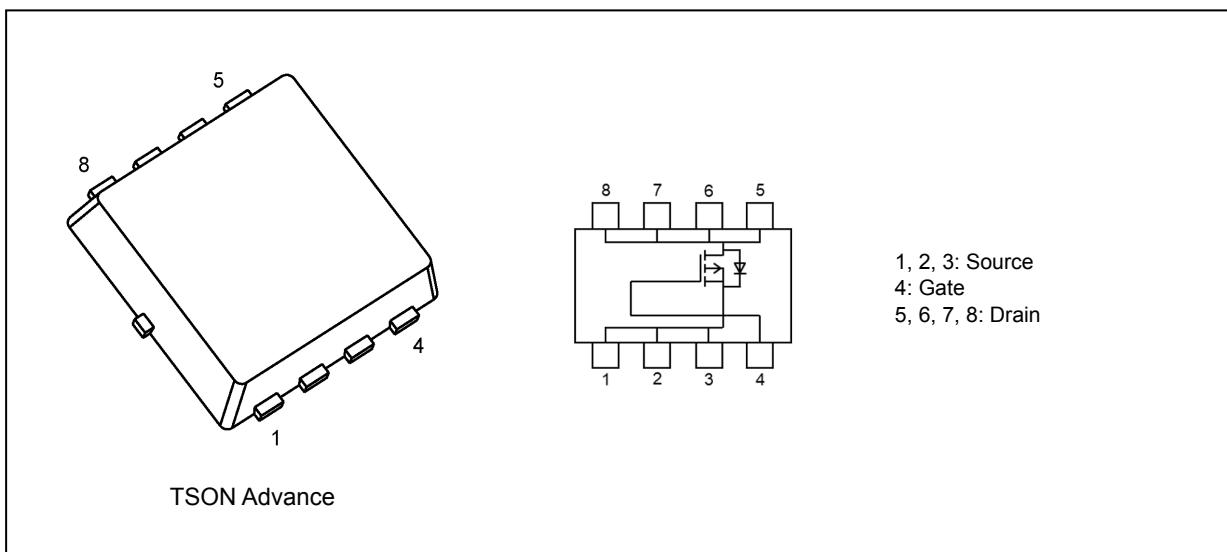
1. Applications

- Power Management Switches

2. Features

- (1) Small, thin package
- (2) Low drain-source on-resistance: $R_{DS(ON)} = 6.0 \text{ m}\Omega$ (typ.) ($V_{GS} = -4.5 \text{ V}$)
- (3) Low leakage current: $I_{DSS} = -10 \mu\text{A}$ (max) ($V_{DS} = -20 \text{ V}$)
- (4) Enhancement mode: $V_{th} = -0.5$ to -1.2 V ($V_{DS} = -10 \text{ V}$, $I_D = -1 \text{ mA}$)

3. Packaging and Internal Circuit



Start of commercial production
2011-10

4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	-20	V
Gate-source voltage	V_{GSS}	± 12	
Drain current (DC)	I_D	-18	A
Drain current (pulsed)	I_{DP}	-54	
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	39	W
Power dissipation ($t = 10 \text{ s}$) (Note 2)	P_D	1.9	W
Power dissipation ($t = 10 \text{ s}$) (Note 3)	P_D	0.7	W
Single-pulse avalanche energy	E_{AS}	211	mJ
Avalanche current	I_{AR}	-18	A
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance ($T_c = 25^\circ\text{C}$)	$R_{th(ch-c)}$	3.2	$^\circ\text{C/W}$
Channel-to-ambient thermal resistance ($t = 10 \text{ s}$) (Note 2)	$R_{th(ch-a)}$	65.7	
Channel-to-ambient thermal resistance ($t = 10 \text{ s}$) (Note 3)	$R_{th(ch-a)}$	178	$^\circ\text{C/W}$

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: $V_{DD} = -16 \text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.5 \text{ mH}$, $R_G = 25 \Omega$, $I_{AR} = -18 \text{ A}$

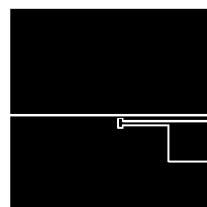


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

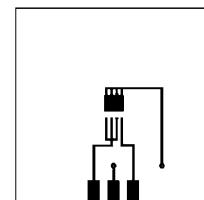


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 12\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = -20\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	-10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -10\text{ mA}$, $V_{GS} = 0\text{ V}$	-20	—	—	
Drain-source breakdown voltage (Note 5)	$V_{(BR)DSX}$	$I_D = -10\text{ mA}$, $V_{GS} = 8\text{ V}$	-12	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = -10\text{ V}$, $I_D = -1\text{ mA}$	-0.5	—	-1.2	
Drain-source on-resistance	$R_{DS(\text{ON})}$	$V_{GS} = -1.8\text{ V}$, $I_D = -4.5\text{ A}$	—	13	42	$\text{m}\Omega$
		$V_{GS} = -2.0\text{ V}$, $I_D = -9\text{ A}$	—	12	21	
		$V_{GS} = -2.5\text{ V}$, $I_D = -9\text{ A}$	—	8.1	11	
		$V_{GS} = -4.5\text{ V}$, $I_D = -18\text{ A}$	—	6.0	7.5	

Note 5: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = -10\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	4165	—	pF
Reverse transfer capacitance	C_{rss}		—	575	—	
Output capacitance	C_{oss}		—	620	—	
Switching time (rise time)	t_r	See Figure 6.2.1.	—	9.2	—	ns
Switching time (turn-on time)	t_{on}		—	17	—	
Switching time (fall time)	t_f		—	145	—	
Switching time (turn-off time)	t_{off}		—	475	—	

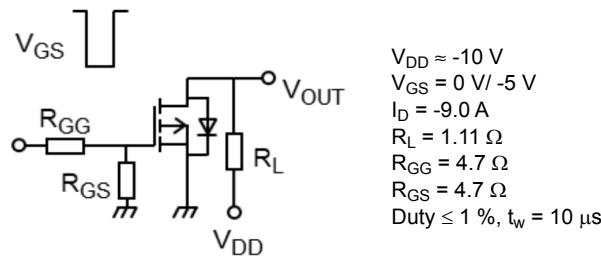


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx -16\text{ V}$, $V_{GS} = -5\text{ V}$, $I_D = -18\text{ A}$	—	63	—	nC
Gate-source charge 1	Q_{gs1}		—	7.5	—	
Gate-drain charge	Q_{gd}		—	20	—	

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 6)	I_{DRP}	—	—	—	-54	A
Diode forward voltage	V_{DSF}	$I_{DR} = -18\text{ A}$, $V_{GS} = 0\text{ V}$	—	—	1.2	V

Note 6: Ensure that the channel temperature does not exceed 150°C .

7. Marking

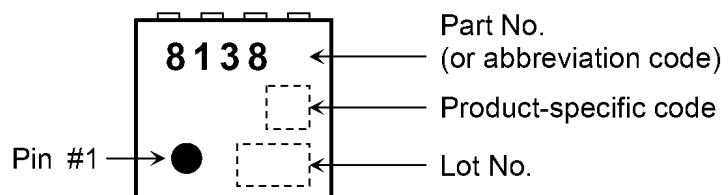
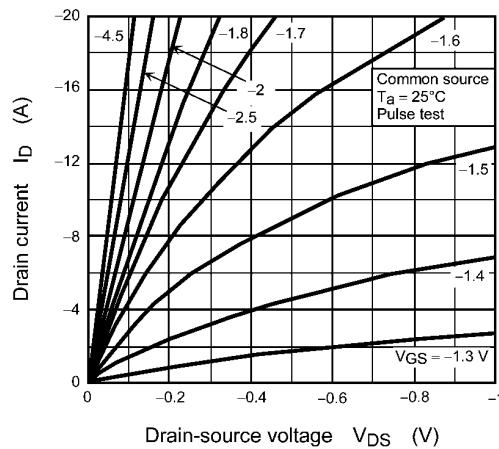
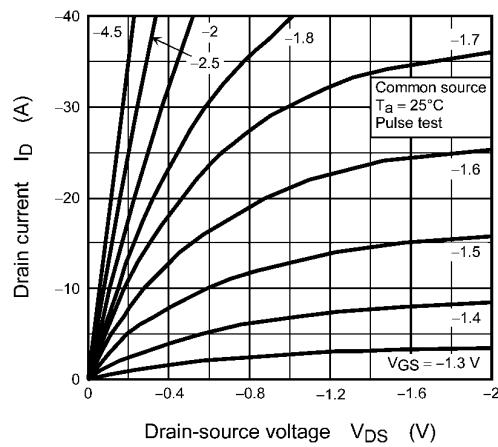
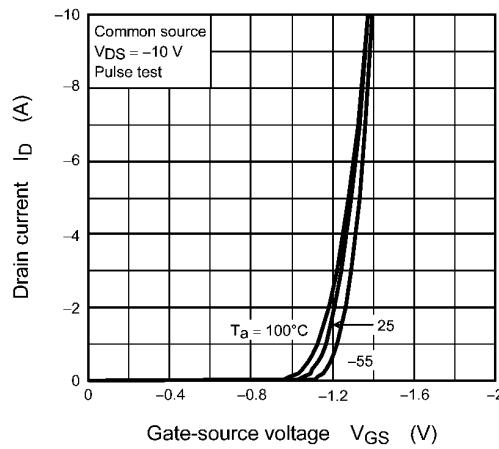
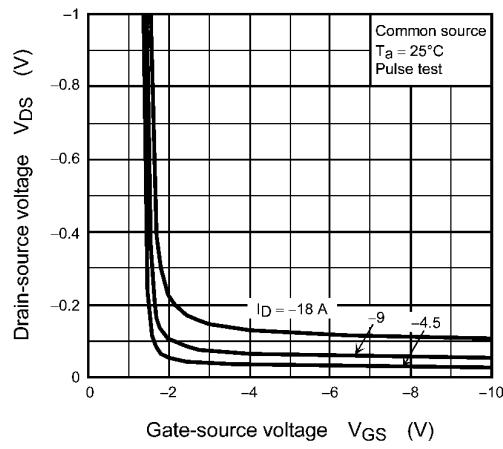
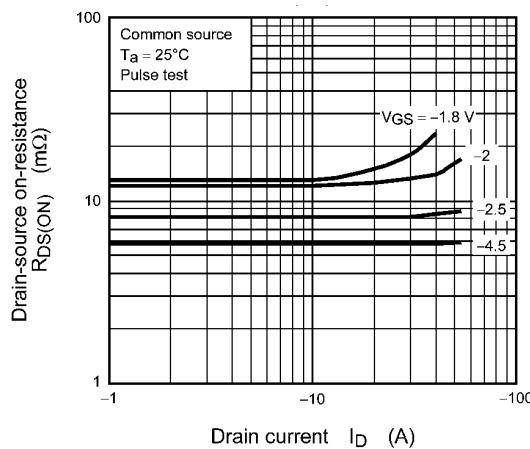
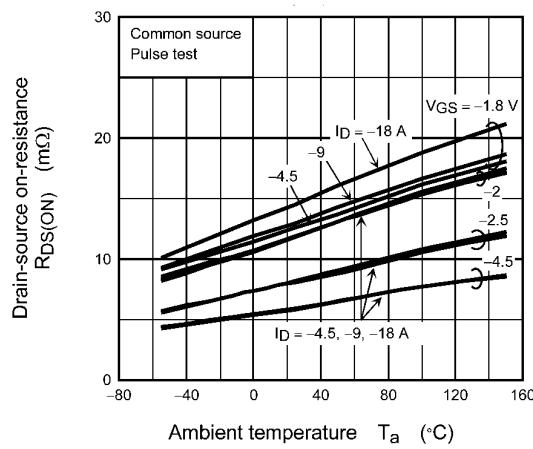


Fig. 7.1 Marking

8. Characteristics Curves (Note)

Fig. 8.1 I_D - V_{DS} Fig. 8.2 I_D - V_{DS} Fig. 8.3 I_D - V_{GS} Fig. 8.4 V_{DS} - V_{GS} Fig. 8.5 $R_{DS(ON)}$ - I_D Fig. 8.6 $R_{DS(ON)}$ - T_a

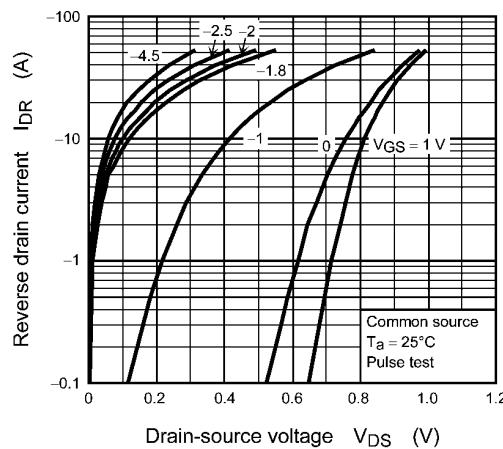


Fig. 8.7 IDR - V_{DS}

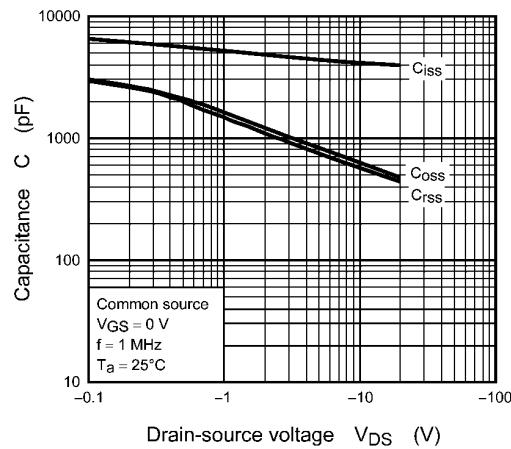


Fig. 8.8 Capacitance - V_{DS}

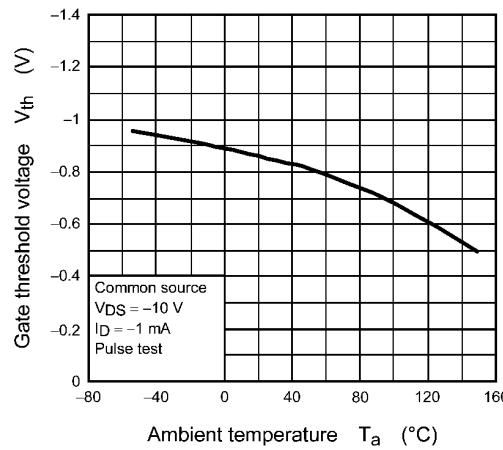


Fig. 8.9 V_{th} - T_a

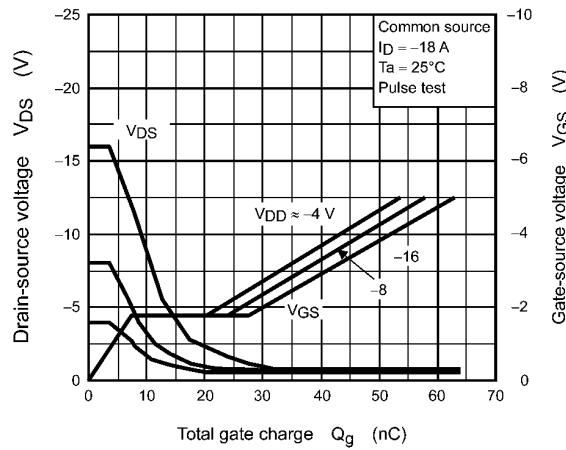


Fig. 8.10 Dynamic Input/Output Characteristics

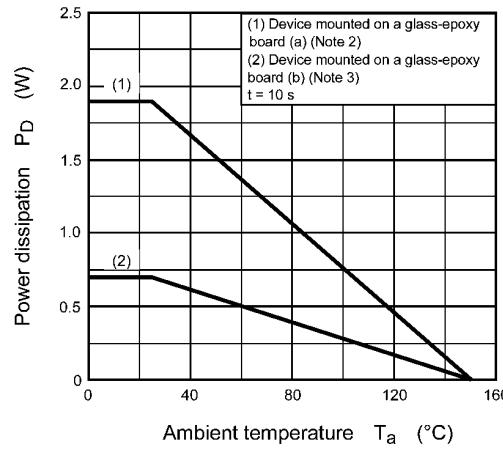


Fig. 8.11 P_D - T_a
(Guaranteed Maximum)

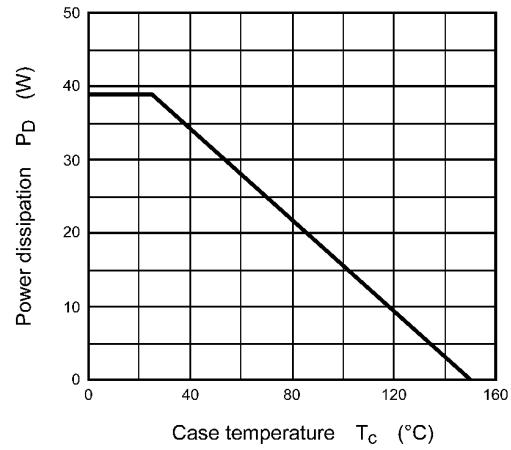
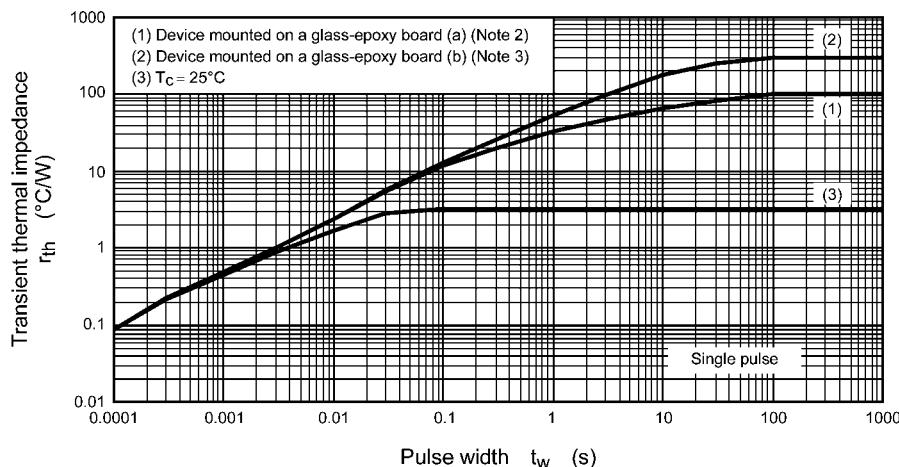
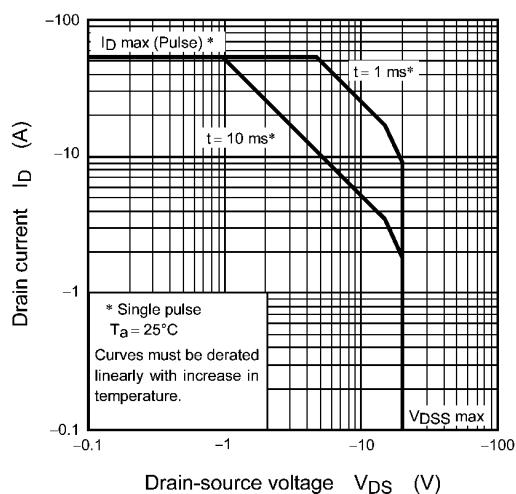


Fig. 8.12 P_D - T_c
(Guaranteed Maximum)



**Fig. 8.13 r_{th} - t_w
(Guaranteed Maximum)**

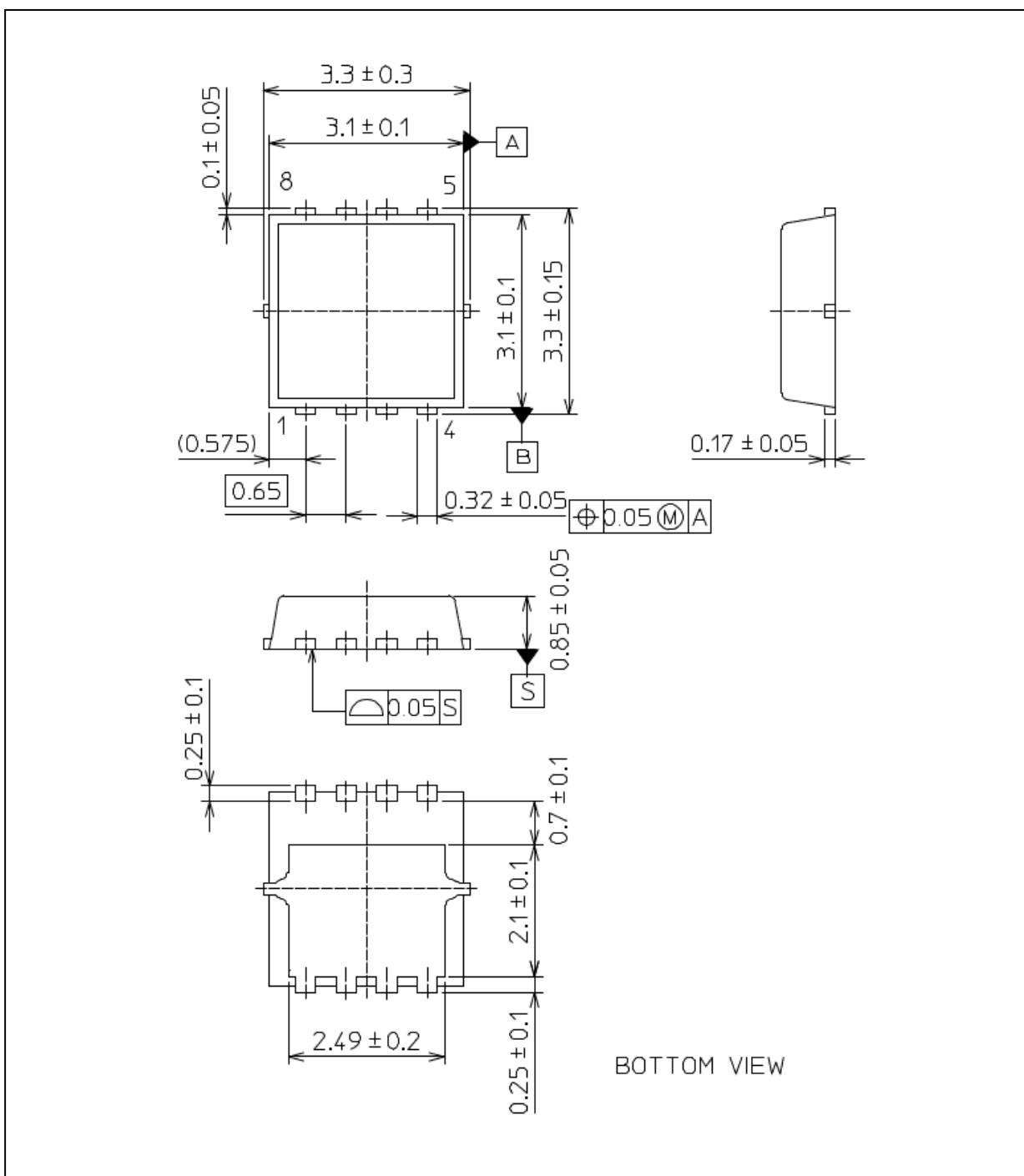


**Fig. 8.14 Safe Operating Area
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.02 g (typ.)

Package Name(s)
TOSHIBA: 2-3X1S
Nickname: TSON Advance

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